

N-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

DESCRIPTION

The μ PA1802 is a switching device which can be driven directly by a 2.5-V power source.

The μ PA1802 features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

FEATURES

- Can be driven by a 2.5-V power source
- Low on-state resistance

$R_{DS(on)1} = 23 \text{ m}\Omega \text{ MAX. (} V_{GS} = 4.5 \text{ V, } I_D = 3.5 \text{ A)}$

$R_{DS(on)2} = 25 \text{ m}\Omega \text{ MAX. (} V_{GS} = 4.0 \text{ V, } I_D = 3.5 \text{ A)}$

$R_{DS(on)3} = 32 \text{ m}\Omega \text{ MAX. (} V_{GS} = 2.5 \text{ V, } I_D = 3.5 \text{ A)}$

ORDERING INFORMATION

| PART NUMBER | PACKAGE |
|--------------------|--------------|
| μ PA1802GR-9JG | Power TSSOP8 |

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

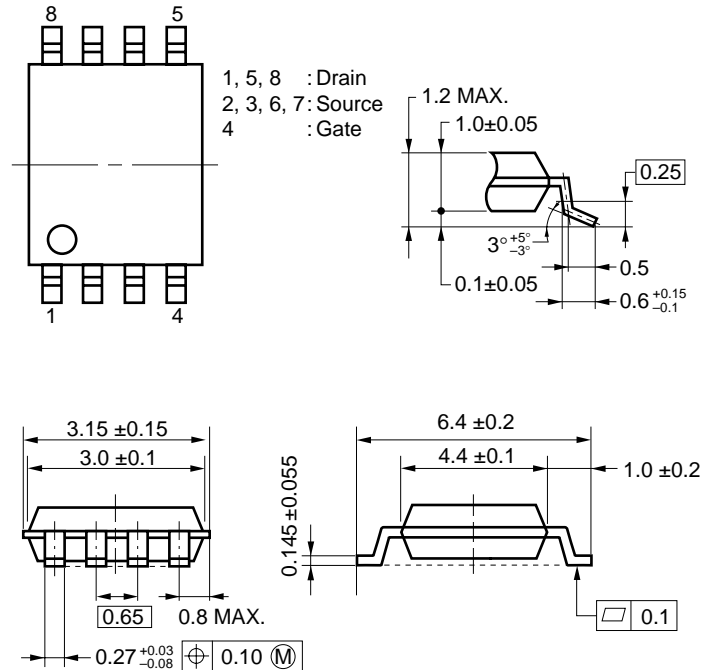
| | | | |
|--|----------------|-------------|------------------|
| Drain to Source Voltage | V_{DSS} | 20 | V |
| Gate to Source Voltage | V_{GSS} | ± 12 | V |
| Drain Current (DC) | $I_{D(DC)}$ | ± 7.0 | A |
| Drain Current (pulse) ^{Note1} | $I_{D(pulse)}$ | ± 28 | A |
| Total Power Dissipation ^{Note2} | P_T | 2.0 | W |
| Channel Temperature | T_{ch} | 150 | $^\circ\text{C}$ |
| Storage Temperature | T_{stg} | -55 to +150 | $^\circ\text{C}$ |

Notes 1. $PW \leq 10 \mu\text{s}$, Duty Cycle $\leq 1\%$

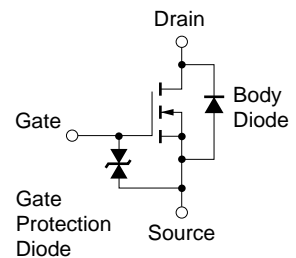
2. Mounted on ceramic substrate of $5000 \text{ mm}^2 \times 1.1 \text{ mm}$

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

PACKAGE DRAWING (Unit : mm)



EQUIVALENT CIRCUIT

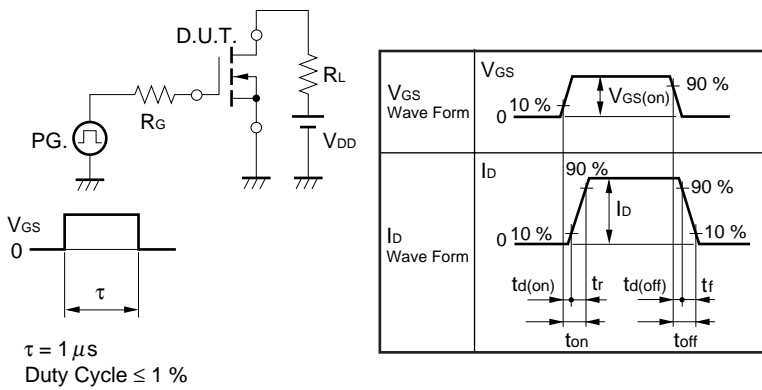


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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

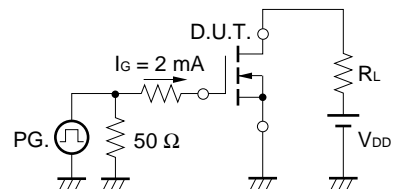
ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

| CHARACTERISTICS | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|---------------------------------------|----------------------|---|------|------|------|------|
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} = 20 V, V _{GS} = 0 V | | | 10 | μA |
| Gate Leakage Current | I _{GSS} | V _{GS} = ±12 V, V _{DS} = 0 V | | | ±10 | μA |
| Gate Cut-off Voltage | V _{GS(off)} | V _{DS} = 10 V, I _D = 1 mA | 0.5 | 0.8 | 1.5 | V |
| ★ Forward Transfer Admittance | y _{fs} | V _{DS} = 10 V, I _D = 3.5 A | 5 | 16 | | S |
| ★ Drain to Source On-state Resistance | R _{DS(on)1} | V _{GS} = 4.5 V, I _D = 3.5 A | | 16 | 23 | mΩ |
| | R _{DS(on)2} | V _{GS} = 4.0 V, I _D = 3.5 A | | 17 | 25 | mΩ |
| | R _{DS(on)3} | V _{GS} = 2.5 V, I _D = 3.5 A | | 21 | 32 | mΩ |
| Input Capacitance | C _{iSS} | V _{DS} = 10 V | | 970 | | pF |
| Output Capacitance | C _{oSS} | V _{GS} = 0 V | | 510 | | pF |
| Reverse Transfer Capacitance | C _{rSS} | f = 1 MHz | | 230 | | pF |
| Turn-on Delay Time | t _{d(on)} | V _{DD} = 10 V | | 60 | | ns |
| Rise Time | t _r | I _D = 3.5 A | | 210 | | ns |
| Turn-off Delay Time | t _{d(off)} | V _{GS(on)} = 4.0 V | | 590 | | ns |
| Fall Time | t _f | R _G = 10 Ω | | 820 | | ns |
| Total Gate Charge | Q _G | V _{DS} = 16 V | | 13 | | nC |
| Gate to Source Charge | Q _{GS} | I _D = 7.0 A | | 3 | | nC |
| Gate to Drain Charge | Q _{GD} | V _{GS} = 4.0 V | | 5 | | nC |
| Diode Forward Voltage | V _{F(S-D)} | I _F = 7.0 A, V _{GS} = 0 V | | 0.74 | | V |

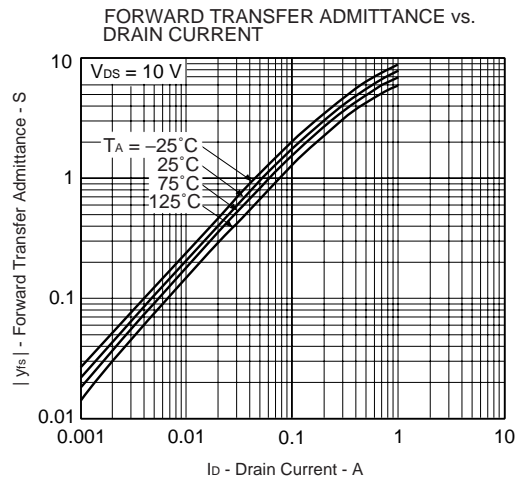
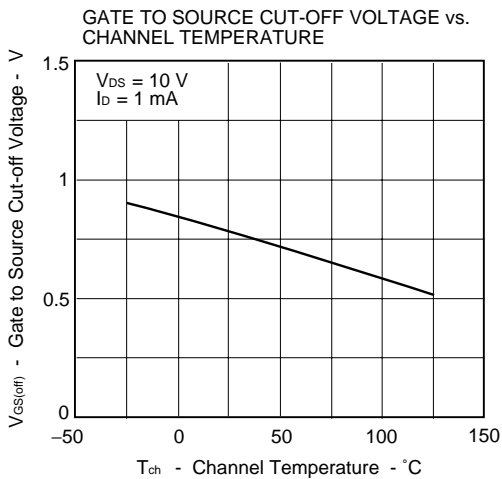
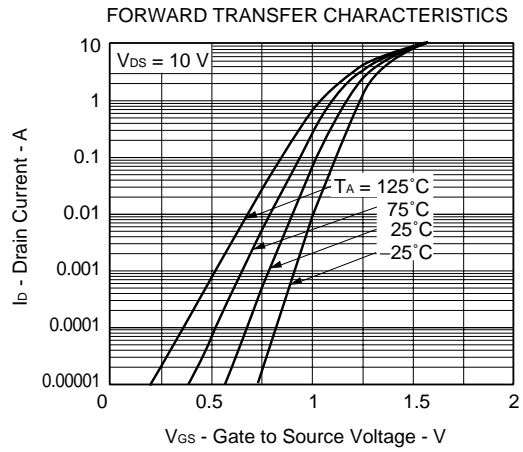
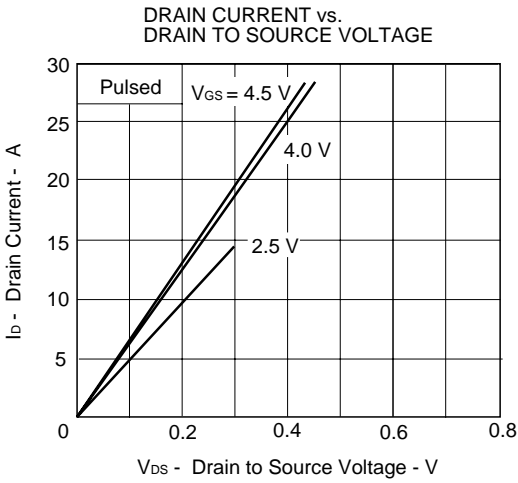
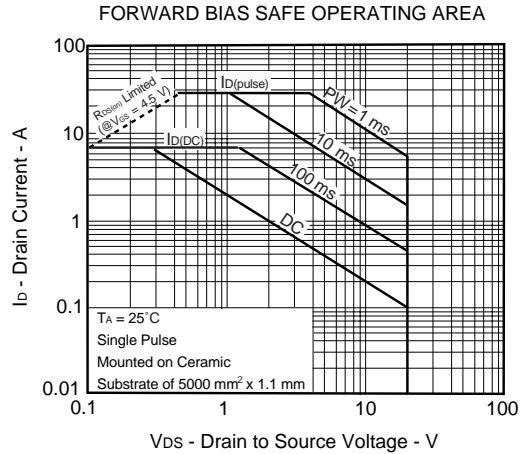
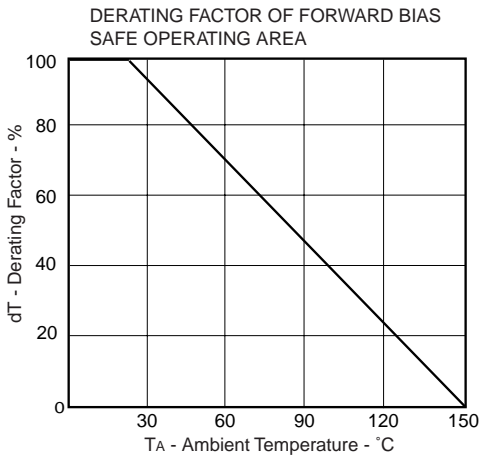
TEST CIRCUIT 1 SWITCHING TIME

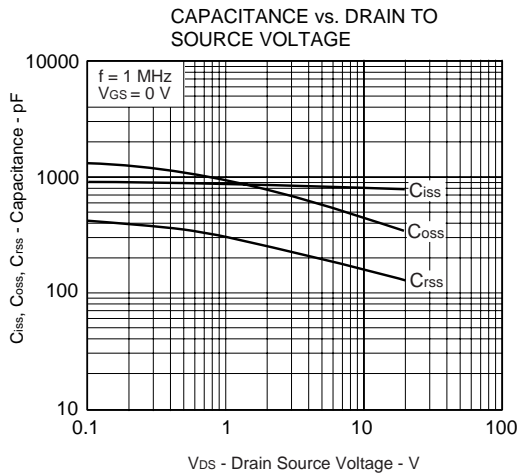
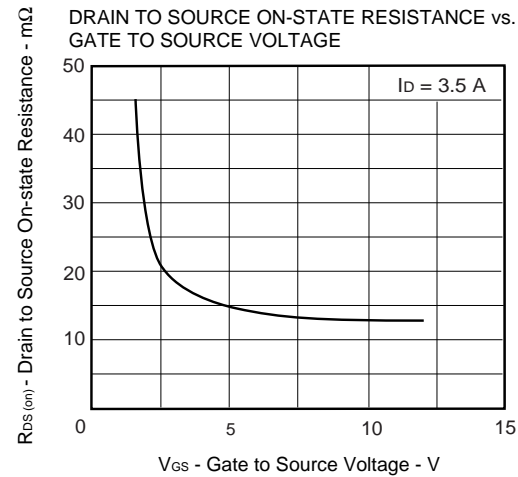
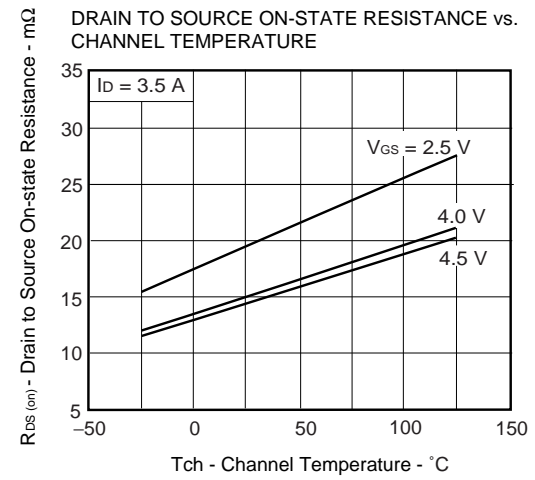
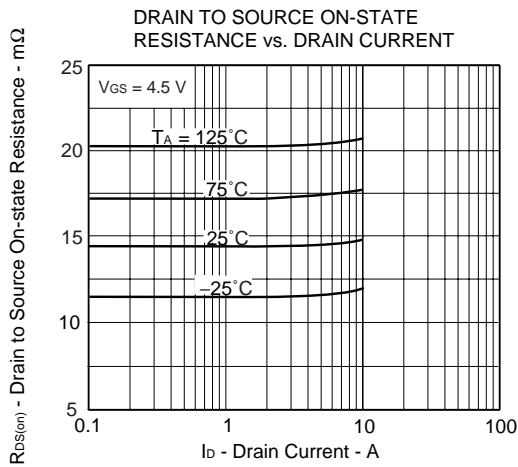
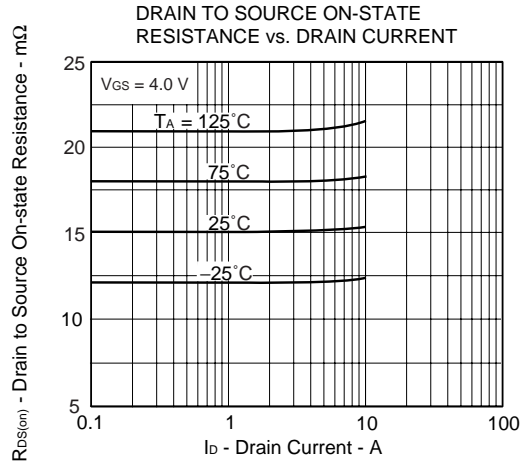
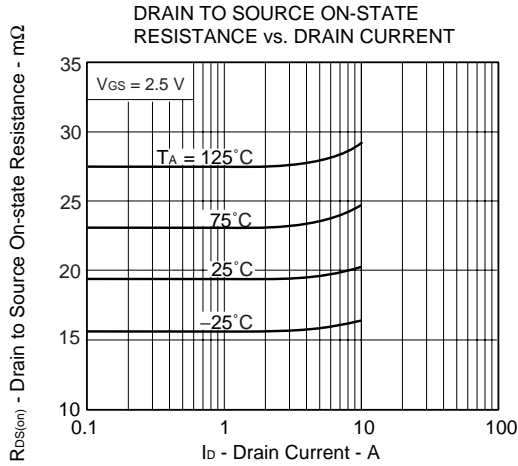


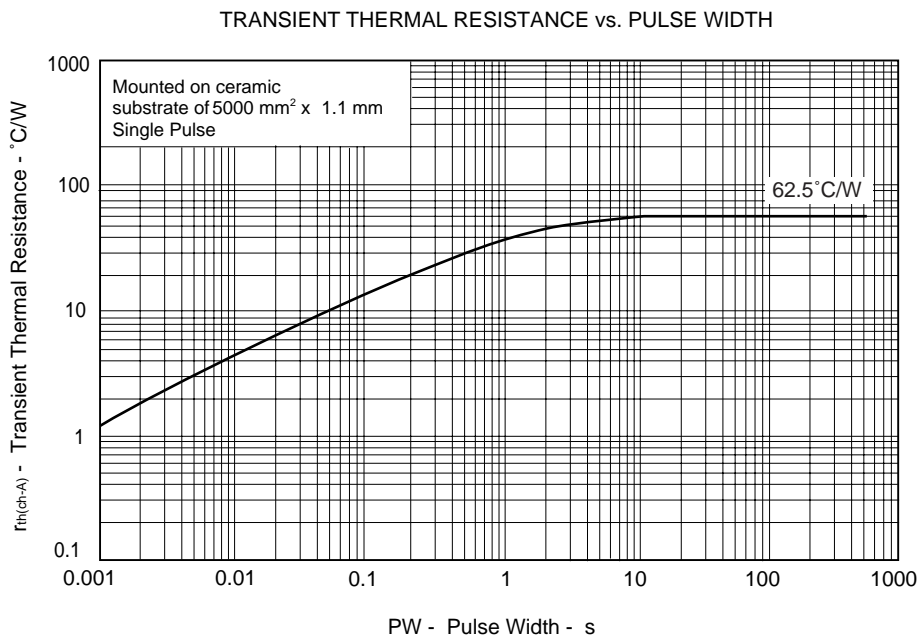
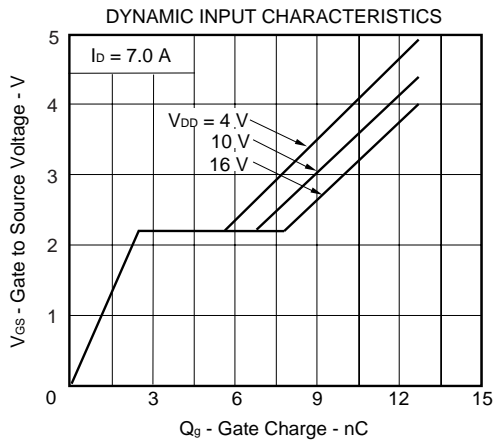
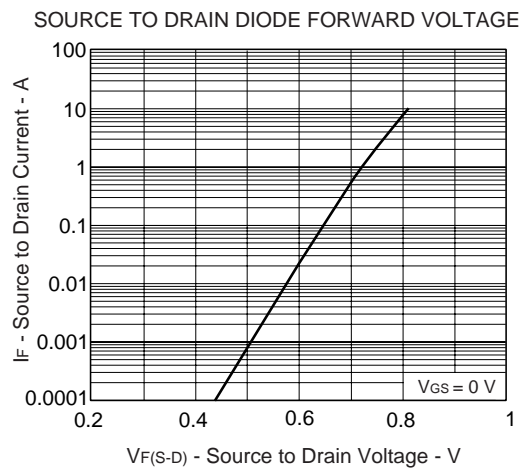
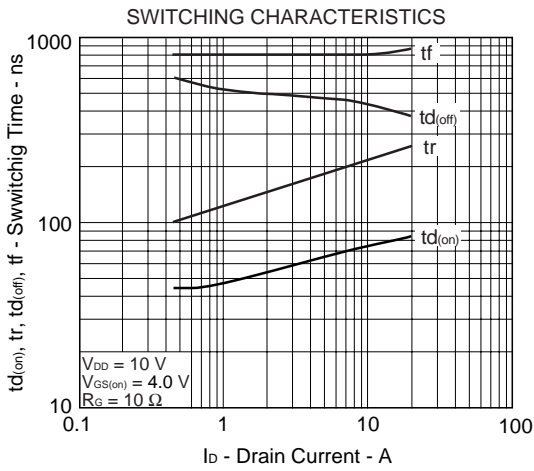
TEST CIRCUIT 2 GATE CHARGE



★ TYPICAL CHARACTERISTICS (T_A = 25 °C)







[MEMO]

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